

HMC668LP3 / 668LP3E

v03.0610



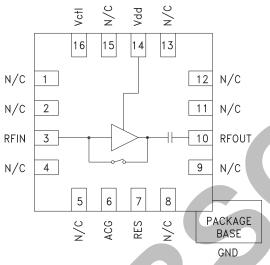
GaAs PHEMT MMIC LNA w/ FAILSAFE BYPASS MODE. 700 - 1200 MHz

Typical Applications

The HMC668LP3(E) is ideal for:

- Cellular/3G and LTE/WiMAX/4G
- BTS & Infrastructure
- · Repeaters and Femtocells
- Tower Mounted Amplifiers
- Test & Measurement Equipment

Functional Diagram



Features

Noise Figure: 0.9 dB Output IP3: +33 dBm

Gain: 16 dB

Failsafe Operation:

Bypass is enabled when LNA is unpowered

Single Supply: +3V or +5V

16 Lead 3x3mm QFN Package: 9 mm²

General Description

The HMC668LP3(E) is a versatile, high dynamic range GaAs MMIC Low Noise Amplifier that integrates a low loss LNA bypass mode on the IC. The amplifier is ideal for receivers and LNA modules operating between 0.7 and 1.2 GHz and provides 0.9 dB noise figure, 16 dB of gain and +33 dBm IP3 from a single supply of +5V @ 57mA. Input and output return losses are excellent and no external matching components are required. A single control line is used to switch between LNA mode and a low loss bypass mode. The failsafe topology enables the LNA bypass path, when no DC power is available. The HMC668LP3(E) offers improved noise figure versus the previously released HMC373LP3(E).

Electrical Specifications, $T_A = +25^{\circ}$ C, Rbias = 0 Ohm

			LNA	Mode			D	unaga Mar	40	E/	siloofo Mo	do	
Parameter	Vdd = +3V		Vdd = +5V		Bypass Mode		Failsafe Mode		Units				
	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	
Frequency Range		0.7 - 1.2			0.7 - 1.2			0.7 - 1.2			0.7 - 1.2		GHz
Gain	12	15		13	16		-2.5	-1.5		-2.5	-1.5		dB
Gain Variation Over Temperature		0.03			0.016			0.0008			0.0008		dB / °C
Noise Figure		0.85	1.1		0.9	1.1							dB
Input Return Loss		12			13			12			12		dB
Output Return Loss		13			14			13			13		dB
Reverse Isolation		22			23			-			-		dB
Power for 1dB Compression (P1dB) ^[1]		13			13			22			24		dBm
Third Order Intercept (IP3)[2]		27			33			26			26		dBm
Supply Current (Idd)		32	40		57	70		0.05			-		mA
Switching Speed (90% -10%)													
LNA Mode to Bypass Mode Bypass Mode to LNA Mode		85			85			200			-		ns ns

^[1] P1dB for LNA Mode is referenced to RFOUT while P1dB for Bypass and Failsafe Modes are referenced to RFIN.

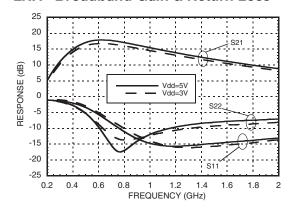
^[2] IP3 for LNA Mode is referenced to RFOUT while IP3 for Bypass and Failsafe Modes are referenced to RFIN.



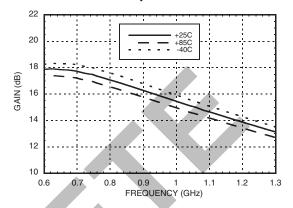


GaAs PHEMT MMIC LNA w/ FAILSAFE BYPASS MODE, 700 - 1200 MHz

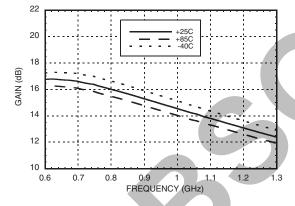
LNA - Broadband Gain & Return Loss



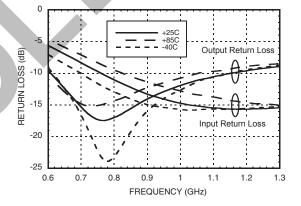
LNA - Gain vs. Temperature [1]



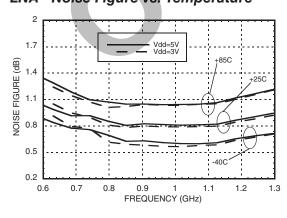
LNA - Gain vs. Temperature [2]



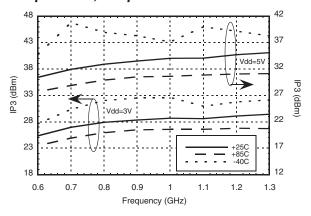
LNA - Return Loss vs. Temperature [1]



LNA - Noise Figure vs. Temperature [3]



LNA - Output IP3 vs.
Temperature, Output Power @ 0 dBm



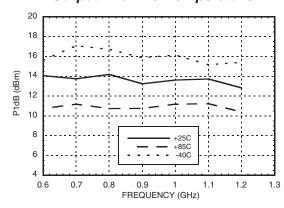
[1] Vdd = 5V [2] Vdd = 3V [3] Measurement reference plane shown on evaluation PCB drawing.



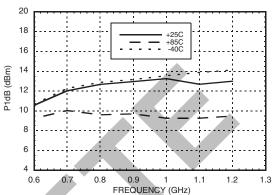


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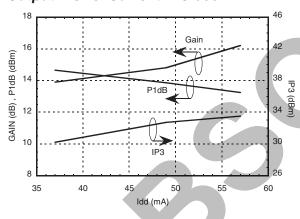
LNA - Output P1dB vs. Temperature [1]



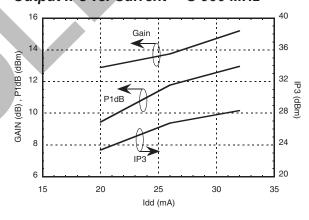
LNA - Output P1dB vs. Temperature [2]



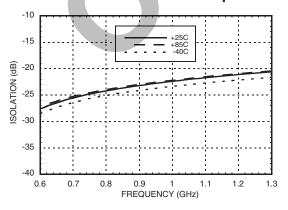
LNA - Gain, P1dB, Output IP3 vs. Current [1] @ 900 MHz



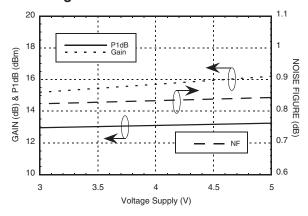
LNA - Gain, P1dB, Output IP3 vs. Current [2] @ 900 MHz



LNA - Reverse Isolation vs. Temperature [1]



LNA - Output P1dB, Gain & Noise Figure [3] vs. Vdd @ 900 MHz



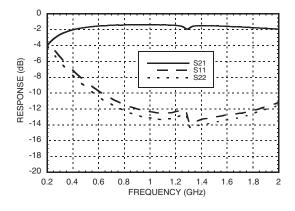
[1] Vdd = 5V [2] Vdd = 3V [3] Measurement reference plane shown on evaluation PCB drawing.



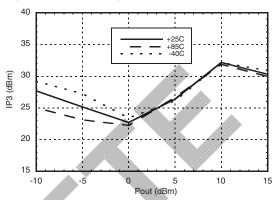


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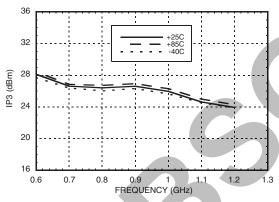
Bypass Mode -Broadband Gain & Return Loss



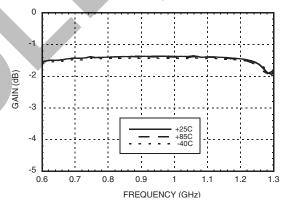
Bypass Mode -Input IP3 vs. Output Power @ 900 MHz



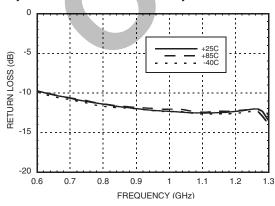
Bypass Mode - Input IP3 vs. Temperature, Output Power @ 5 dBm



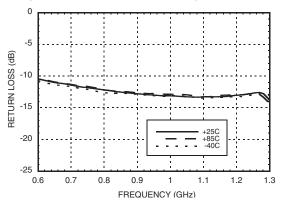
Bypass Mode -Insertion Loss vs. Temperature



Bypass Mode -Input Return Loss vs. Temperature



Bypass Mode -Output Return Loss vs. Temperature



GaAs PHEMT MMIC LNA w/

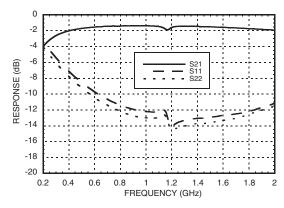


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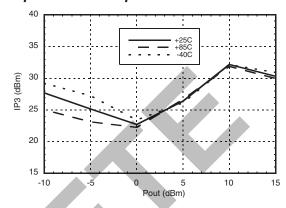
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Failsafe Mode -Broadband Gain & Return Loss

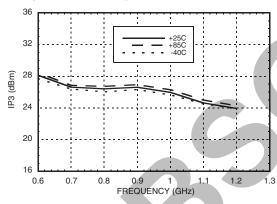


Failsafe Mode - Input IP3 vs. Output Power @ 900 MHz

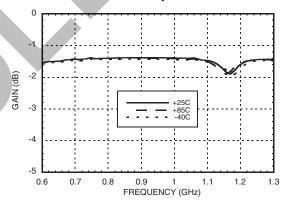
FAILSAFE BYPASS MODE, 700 - 1200 MHz



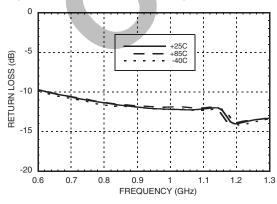
Failsafe Mode - Input IP3 vs. Temperature, Output Power @ 5 dBm



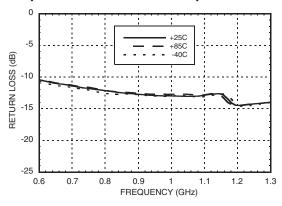
Failsafe Mode - Insertion Loss vs. Temperature



Failsafe Mode -Input Return Loss vs. Temperature



Failsafe Mode -Output Return Loss vs. Temperature



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Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+6 Vdc
Control Voltage (Vctl)	+6 Vdc
RF Input Power (RFIN) LNA Mode Bypass / Failsafe Mode	+5 dBm +20 dBm
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 10.71 mW/°C above 85 °C)	0.70 W
Thermal Resistance (channel to ground paddle)	93.33 °C/W
Storage Temperature	-65 to +150° C
Operating Temperature	-40 to +85° C
ESD Sensitivity (HBM)	Class 1A



Typical Supply Current vs. Vdd

	Rbias Ω	Idd (mA)				
		Vdd= 3V	Vdd= 5V			
	0	32	57			
	15	26	49			
	47	20	37			
	180 [1]	10	20			

^[1] Recommended maximum Rbias

Truth Table

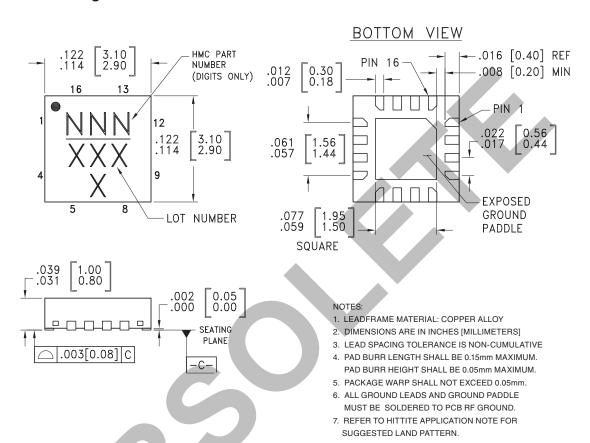
LNA Mode	Vctl = Vdd = 3 to 5V
Bypass Mode	Vctl= 0V, Vdd = 3 to 5V
Failsafe Mode	VctI = Vdd = N/C





GaAs PHEMT MMIC LNA w/ FAILSAFE BYPASS MODE, 700 - 1200 MHz

Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC668LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	668 XXXX
HMC668LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	668 XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX





GaAs PHEMT MMIC LNA w/ FAILSAFE BYPASS MODE, 700 - 1200 MHz

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 2, 4, 5, 8, 9, 11, 12, 13, 15	N/C	No connection required. These pins may be connected to RF GND. Performance will not be affected.	
3	RFIN	This pin is DC coupled. Off-chip DC blocking capacitor required.	RFINO
6	ACG	AC Ground. Attach bypass capacitor per application circuit.	ļ ļ
7	RES	External resistor pin for current control. See table for external resistor value vs. bias current data.	ESD ACG RES
10	RFOUT	This pin is matched to 50 Ohms	RFOUT
14	Vdd	Power Supply voltage pin. External bypass capacitors required.	Vdd ♀
16	VctI	Control voltage pin for LNA / Bypass Modes. Setting voltage equal to VDD enables LNA Mode. External Bypass capacitor required.	VctI ESD =

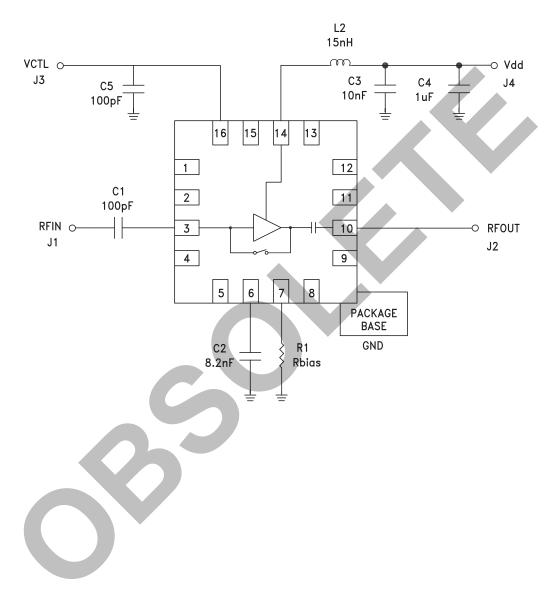
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Application Circuit



GaAs PHEMT MMIC LNA w/

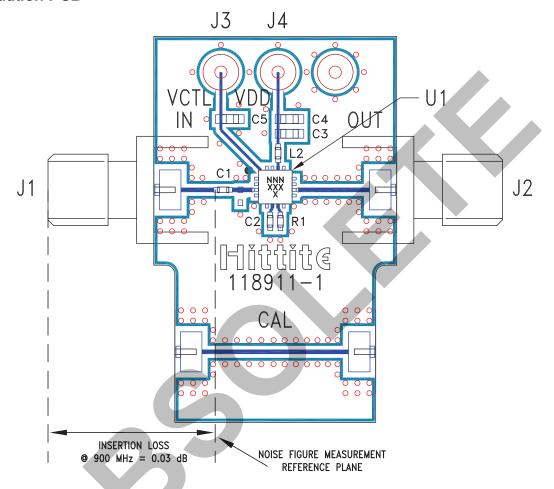


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FAILSAFE BYPASS MODE, 700 - 1200 MHz

Evaluation PCB



List of Materials for Evaluation PCB 121922 [1]

Item	Description		
item	Description		
J1 - J2	PCB Mount SMA Connector		
J3 - J4	DC Pin		
C1	100 pF Capacitor, 0402 Pkg.		
C2	8200 pF Capacitor, 0402 Pkg.		
C3	10 nF Capacitor, 0603 Pkg.		
C4	1 μF Capacitor, 0603 Pkg.		
C5	100 pF Capacitor, 0603 Pkg.		
L2	15 nH Inductor, 0402 Pkg.		
R1	0 Ohm Resistor, 0402 Pkg.		
U1	HMC668LP3(E) Amplifier		
PCB [2]	118911 Evaluation Board		

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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